MP-04

## Controlled Wall Thickness of Cu/Al<sub>2</sub>O<sub>3</sub> Nanocables by Using Atomic Layer Deposition and Electrodeposition

Moon C. Kang, Jae K. Hwang, Myung M. Sung\*

Department of Chemistry, Kookmin University

We have been studied the fabrication of Cu/Al<sub>2</sub>O<sub>3</sub> nanocables by using atomic layer deposition (ALD) and electrodeposition with a nanoporous polycarbonate (PC) membrane as the template. The Al<sub>2</sub>O<sub>3</sub> nanotubes were successfully coated only onto the inner-wall of PC template by ALD at 413K. The Al<sub>2</sub>O<sub>3</sub> wall thickness controlled by ALD cycle and Cu nanowires arrays were electrodeposited into the Al<sub>2</sub>O<sub>3</sub> nanotubes and the PC filters were etched away using the solution of chloroform. The Cu/Al<sub>2</sub>O<sub>3</sub> nanocables have been investigated by scanning electron microscopy (SEM) and transmission electron microscopy (TEM).